Appl. No. 10/659,415 Amdt. dated July 14, 2005 Reply to Office action of April 18, 2005

## Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

## **Listing of the Claims:**

1. (currently amended) A method of stud bumping, comprising:

providing a bonding head having a plurality of wire passages formed therein;

disposing a plurality of wires through respective ones of the plurality of wire passages;

providing a substrate having a plurality of bond pads;

engaging the <u>plurality of</u> wires <u>substantially simultaneously</u> with respective ones of a first set of the bond pads; and

forming a first set of stud bumps <u>substantially simultaneously</u> outwardly from respective ones of the first set of the bond pads.

- 2. (original) The method of Claim 1, wherein the bonding head is formed from a ceramic.
- 3. (original) The method of Claim 1, wherein the wires are formed from a material selected from the group consisting of gold and aluminum.
- 4. (original) The method of Claim 1, further comprising causing a pitch between any two adjacent wire passages to be no more than 1000 microns.
- 5. (original) The method of Claim 1, further comprising causing a pitch between any two adjacent wire passages to be no more than 200 microns.
- 6. (original) The method of Claim 1, further comprising causing the wire passages to resemble an array selected from the group consisting of a linear array and a rectangular array.
- 7. (original) The method of Claim 1, wherein the engaging and forming steps

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are each performed simultaneously.

- 8. (original) The method of Claim 1, further comprising forming a second set of stud bumps outwardly from respective ones of a second set of the bond pads.
- 9. (original) A system for stud bumping, comprising:

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a bonding head having a plurality of wire passages formed therein;

a plurality of wires disposed through respective ones of the plurality of wire passages;

a substrate having a plurality of bond pads; and

a robot coupled to the bonding head, the robot operable to form a first set of stud bumps outwardly from respective ones of a first set of the bond pads.

- 10. (original) The system of Claim 9, wherein the bonding head is formed from a ceramic.
- 11. (original) The system of Claim 9, wherein the wires are formed from a material selected from the group consisting of gold and aluminum.
- 12. (original) The system of Claim 9, wherein a pitch between any two adjacent wire passages is no more than 1000 microns.
- 13. (original) The system of Claim 9, wherein a pitch between any two adjacent wire passages is no more than 200 microns.
- 14. (original) The system of Claim 9, wherein the wire passages resemble an array selected from the group consisting of a linear array and a rectangular array.
- 15. (original) The system of Claim 9, wherein the robot is operable to simultaneously engage the wires with respective ones of the bond pads to form the stud bumps.
- 16. (original) The system of Claim 9, further comprising forming a second set of stud bumps outwardly from respective ones of a second set of the bond pads.

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17. (original) A bonding head for simultaneously forming a plurality of stud bumps outwardly from respective ones of a plurality of bond pads formed on a substrate, comprising:

a generally rectangular body;

an array of wire passages formed in the body, each wire passage configured to accept a wire, the array selected from the group consisting of a linear array and a rectangular array; and

wherein a pitch between any two adjacent wire passages is no more than 1000 microns..

- 18. (original) The bonding head of Claim 17, wherein the body is formed from a ceramic.
- 19. (original) The bonding head of Claim 17, wherein the wires are formed from a material selected from the group consisting of gold and aluminum.
- 20. (original) The bonding head of Claim 17, wherein a pitch between any two adjacent wire passages is no more than 200 microns.